

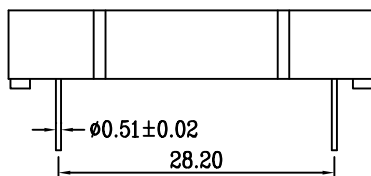
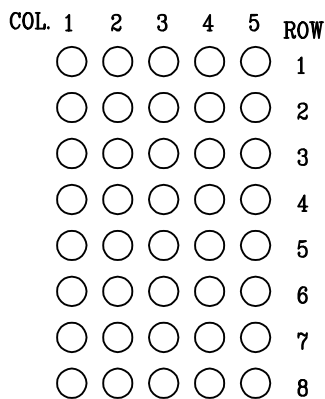
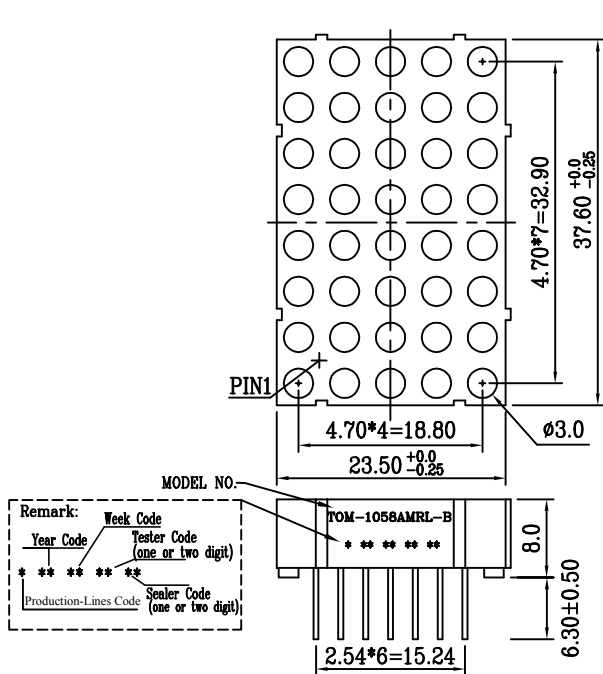


# TAIWAN OASIS LED DATA SHEET

PART NO. : TOM-1058AMRL-B

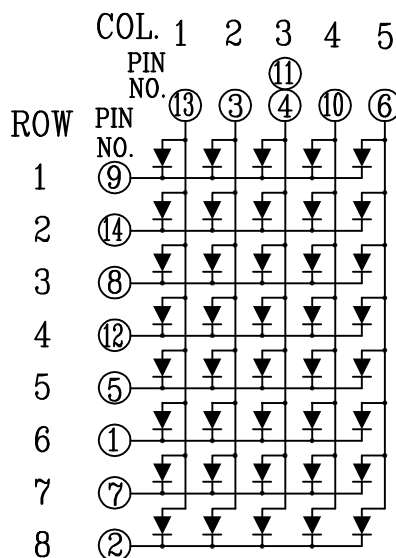
APPEARANCE			TECHNOLOGIE	AlGaInP/GaAs
FACE	SEGMENT	PIN	SOURCE COLOR	Ultra-Red
Black	White	∅0.51x10.28	DRIVER MODE	Row. Cathode
			PACKING	Tube

## PACKAGE DIMENSIONS



NORMAL TOLERANCE: ±0.25 ANGLE: ±1°

## INTERNAL CIRCUIT DIAGRAM



DATE	10/26/07'	SCALE	2.5:1	DRAWING NO.	S-1058AMRL-B-A	DRAWN	L.D.Y	CHECKED	
UNIT	M/M	SHEET NO.	1/2			CUSTOMER		APPROVED	



# TAIWAN OASIS LED DATA SHEET

PART NO. : TOM-1058AMRL-B

ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	VALUE	UNITS
Power Dissipation Per Dot	60	mW
Peak Forward Current Per Dot (1/10 Duty Cycle, 0.1ms Pulse Width)	80	mA
Continuous Forward Current Per Dot	20	mA
Recommend Operating Current	15	mA
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-25 to +85	°C
Storage Temperature Range	-30 to +85	°C
Junction Temperature	>85	°C
Lead Free Solder Temperature(1/16 Inch Below Seating Plane)	260°C for 3 sec.	

ELECTRICAL/OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITION
Luminous Intensity Per Dot	I <sub>v</sub>	10384	15524		ucd	I <sub>F</sub> = 10mA
Dominant Emission Wavelength	λ <sub>d</sub>		640		nm	I <sub>F</sub> = 20mA
Spectral Line Half-Width	Δλ		15		nm	I <sub>F</sub> = 20mA
Forward Voltage Per Dot	V <sub>F</sub>	1.8	2.0	2.3	V	I <sub>F</sub> = 20mA
Reverse Current Per Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> = 5V
Luminous Intensity Matching Rate	I <sub>v</sub> -m			2.0:1		I <sub>F</sub> = 20mA

Notes: Above specification may be changed without notice.

DATE	10/26/07'	SCALE	_____	DRAWING NO.	S-1058AMRL-B-A	DRAWN	L.D.Y	CHECKED	
UNIT	_____	SHEET NO.	2/2			CUSTOMER		APPROVED	